

4 PIN DIP PHOTOTRANSISTOR PHOTOCOUP EL816 Series



Features:

- Compliance Halogens Free (Only copper leadframe) (Br < 900 ppm, Cl < 900 ppm, Br+Cl < 1500 ppm)
- Current transfer ratio (CTR: 50~600% at $I_F = 5mA$, $V_{CE} = 5V$) (CTR: 62, 220% at $I_F = 10mA$, $V_{CE} = 5V$)
- (CTR: 63~320% at I_F = 10mA, V_{CE} = 5V) • High isolation voltage between input and output (Viso=5000Vrms)
- Creepage distance > 7.62mm
- Operating temperature up to +110°C
- Compact small outline package
- The product itself will remain within RoHS compliant version
- Compliance with EU REACH
- UL and cUL approved(No. E214129)
- VDE approved (No. 132249)
- SEMKÖ approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

Description

The EL816 series of devices each consist of an infrared emitting diodes,

optically coupled to a phototransistor detector.

They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

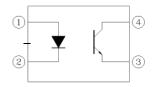
Applications

- Programmable controllers
- System appliances, measuring instruments
- Telecommunication equipments
- Home appliances, such as fan heaters, etc.
- · Signal transmission between circuits of different potentials and impedances

Schematic

XA

Switch Connector



Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
	Forward current	١ _F	60	mA
	Peak forward current (1us, pulse)	I _{FP}	1	А
Input	Reverse voltage	V _R	6	V
	Power Dissipation No derating required up to $T_a = 100^{\circ}C$	P _D	100	mW
	Power dissipation	_	150	mW
	Derating factor (above $T_a = 80^{\circ}C$)	P _C —	5.8	mW/°C
Output	Collector current	Ι _C	50	mA
	Collector-Emitter voltage	V _{CEO}	80	V
	Emitter-Collector voltage	V _{ECO}	6	V
Total Powe	Total Power Dissipation		200	mW
Isolation V	Isolation Voltage*1		5000	Vrms
Operating	Operating Temperature		-55 to 110	°C
Storage Te	Storage Temperature		-55 to 125	°C
Soldering Temperature* ²		T _{SOL}	260	°C

Notes:

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together. *2 For 10 seconds

Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

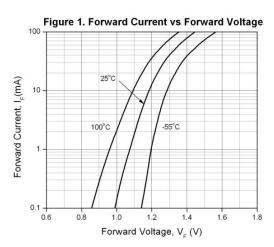
Input							
Parameter		Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage		V _F	-	1.2	1.4	V	I _F = 20mA
Reverse Current		I _R	-	-	10	μA	$V_R = 4V$
Input capacitance		C _{in}	-	30	250	pF	V = 0, f = 1kHz
Output							
Param	eter	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Emitt current	ter dark	I _{CEO}	-	-	100	nA	$V_{CE} = 20V, I_F = 0mA$
Collector-Emit breakdown vo		BV _{CEO}	80	-	-	V	$I_{\rm C} = 0.1 {\rm mA}$
Emitter-Collec breakdown vo		BV _{ECO}	6	-	-	V	I _E = 0.1mA
Transfer Cha	aracteristic	s					
Param	eter	Symbol	Min	Тур.	Max.	Unit	Condition
	EL816		50	-	600		
					600		
	EL816A		80	-	160		
	EL816A EL816B		80 130	-			
		CTR			160	%	I _F = 5mA ,V _{CE} = 5V
	EL816B	 CTR	130	-	160 260	%	I _F = 5mA ,V _{CE} = 5V
	EL816B EL816C		130 200	-	160 260 400	%	I _F = 5mA ,V _{CE} = 5V
Current	EL816B EL816C EL816D	CTR	130 200 300	-	160 260 400 600	%	I _F = 5mA ,V _{CE} = 5V
Current Transfer ratio	EL816B EL816C EL816D EL816X	CTR	130 200 300 100	- - - -	160 260 400 600 200	%	I _F = 5mA ,V _{CE} = 5V
	EL816B EL816C EL816D EL816X EL816Y		130 200 300 100 150	- - - -	160 260 400 600 200 300	%	$I_F = 5mA$, $V_{CE} = 5V$ $I_F = 10mA$, $V_{CE} = 5V$
	EL816B EL816C EL816D EL816X EL816Y EL816I		130 200 300 100 150 63	- - - - - -	160 260 400 600 200 300 125		
	EL816B EL816C EL816D EL816X EL816Y EL816I EL816J	- CTR -	130 200 300 100 150 63 100	- - - - - -	160 260 400 600 200 300 125 200	%	
	EL816B EL816C EL816D EL816X EL816Y EL816I EL816J EL816K		130 200 300 100 150 63 100 160	- - - - - - -	160 260 400 600 200 300 125 200 320		

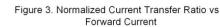
Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Emitter saturation voltage	V _{CE(sat)}	-	0.1	0.2	V	$I_{F} = 20mA$, $I_{C} = 1mA$
Isolation resistance	R _{IO}	5×10 ¹⁰	-	-	Ω	V _{IO} = 500Vdc, 40~60% R.H.
Floating capacitance	C _{IO}	-	0.6	1.0	pF	$V_{IO} = 0$, f = 1MHz
Cut-off frequency	fc	-	80	-	kHz	$V_{CE} = 5V, I_C = 2mA$ $R_L = 100\Omega, -3dB$
Rise time	t _r	-	4	18	μs	$V_{CE} = 2V, I_{C} = 2mA,$
Fall time	t _f	-	3	18	μs	$R_L = 100\Omega$

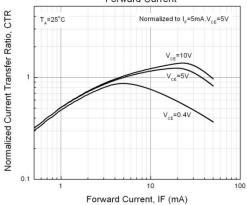
Transfer Characteristics (T_a=25°C unless specified otherwise) Continuity

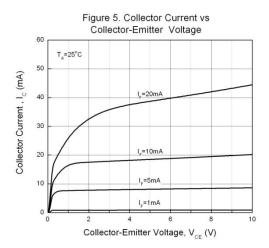
* Typical values at $T_a = 25^{\circ}C$

Typical Electro-Optical Characteristics Curves









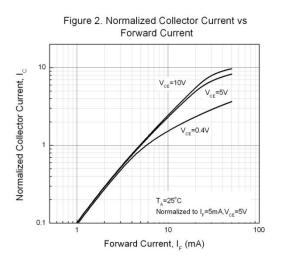
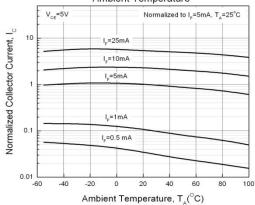
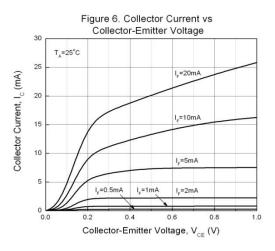
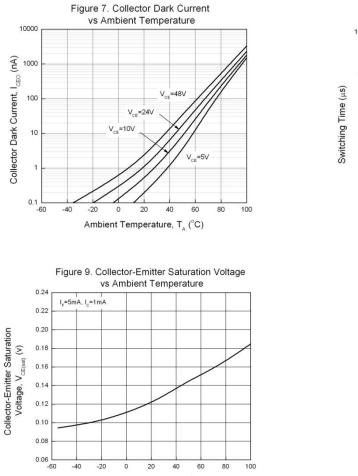


Figure 4. Normalized Collector Current vs Ambient Temperature

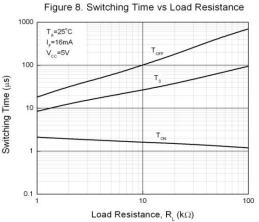






-40 -20 0 20 40 60 80 100

Ambient Temperature (°C)



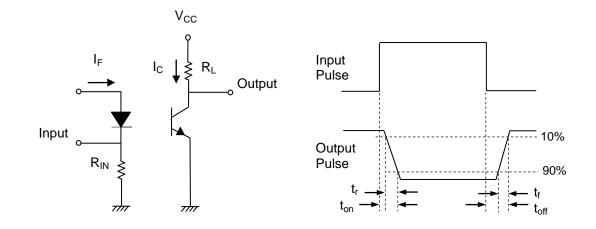


Figure 10. Switching Time Test Circuit & Waveforms

Order Information

Part Number

EL816X(Y)(Z)-FV

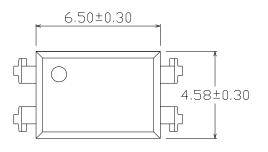
Note

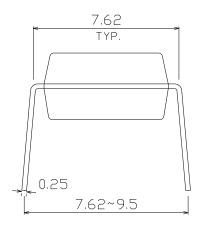
- Х = Lead form option (S1, S2, M or none)
- = CTR Rank (A, B, C, D, X, Y, I, J, K or none) = Tape and reel option (TU, TD or none). Υ
- Ζ
- F = Lead frame option (F: Iron, None: copper)
- V = VDE safety (optional).

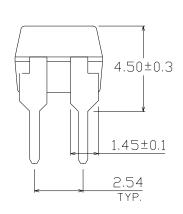
Option	Description	Packing quantity
None	Standard DIP-4	100 units per tube
М	Wide lead bend (0.4 inch spacing)	100 units per tube
S1 (TU)	Surface mount lead form (low profile) + TU tape & reel option	1500 units per reel
S1 (TD)	Surface mount lead form (low profile) + TD tape & reel option	1500 units per reel
S2 (TU)	Surface mount lead form (low profile) + TU tape & reel option	2000 units per reel
S2 (TD)	Surface mount lead form (low profile) + TD tape & reel option	2000 units per reel

Package Dimension (Dimensions in mm)

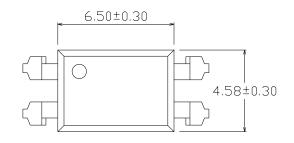
Standard DIP Type

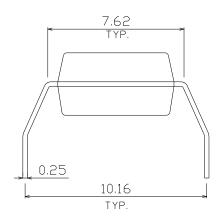


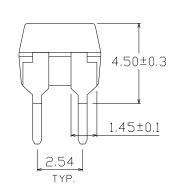




Option M Type

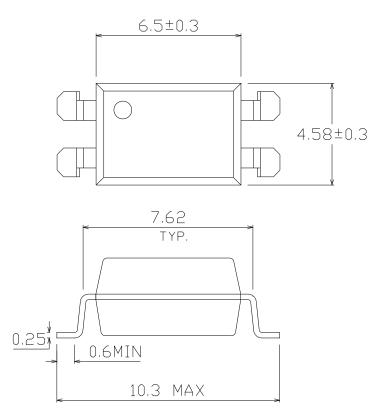


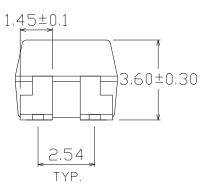




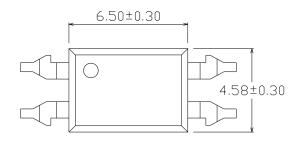
DATASHEET 4PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER EL816 series

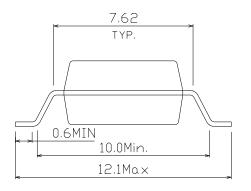
Option S1 Type

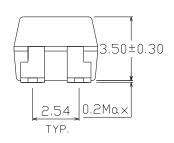




Option S2 Type

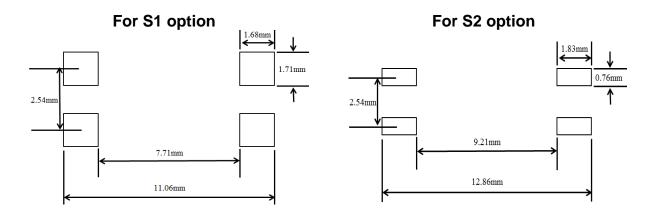




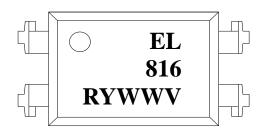


DATASHEET 4PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER EL816 series

Recommended pad layout for surface mount leadform



Device Marking

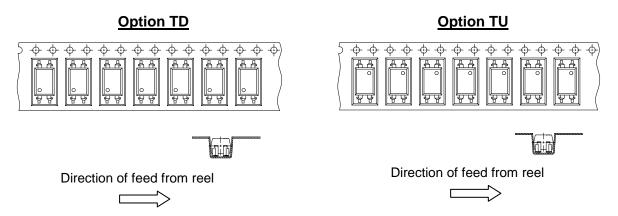




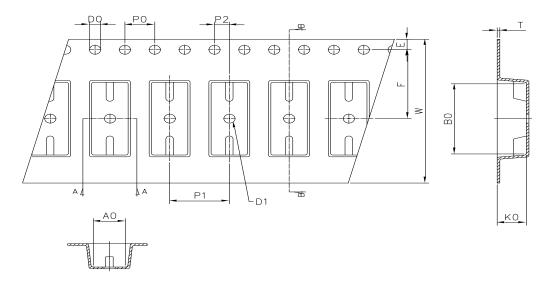
Notes

EL	denotes XI BNANG 816
denotes E	Device Number
R	denotes CTR Rank(A, B, C, D, X, Y, I, J, K or none
) Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

Tape & Reel Packing Specifications



Tape dimensions

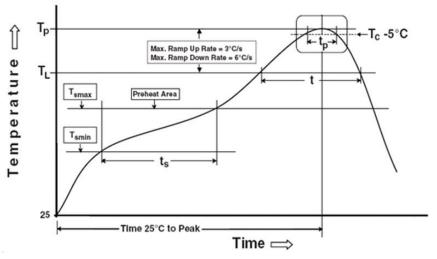


Dimension No.	Ао	Во	Do	D1	E	F
Dimension (mm) S1	4.90±0.1	10.40±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.50±0.1
Dimension (mm) S2	4.88±0.1	12.55±0.1	1.5±0.1	1.50±0.1	1.75±0.1	11.5±0.1
Dimension No.	Ро	P1	P2	t	w	Ко
Dimension (mm)						
S1	4.00±0.1	8.00±0.	2.00±0.1	0.40±0.1	16.00±0.3	4.60±0.1

Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Preheat

150
200°
60-1 3 °C

Liquidus Temperature (T _L)
Time above Liquidus Temperature (t $_{L}$)
Peak Temperature (T _P)
Time within 5 °C of Actual Peak Temperature: T_P - 5°C
Ramp- Down Rate from Peak Temperature
Time 25°C to peak temperature Reflow times

Reference: IPC/JEDEC J-STD-020D

150 °C 200°C 60-120 seconds 3 °C/second max

217 °C 60-100 sec 260°C 30 s 6°C /second max. 8 minutes max. 3 times

DISCLAIMER

- 1. Above specification may be changed without notice. XI BNANG will reserve authority on material change for above specification.
- 2. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
- 3. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. XI BNANG assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
- 4. These specification sheets include materials protected under copyright of XI BNANG. Reproduction in any form is prohibited without the specific consent of XI BNANG.
- 5. This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or life saving applications or any other application which can result in human injury or death. Please contact authorized XI BNANG sales agent for special application request.
- 6. Statements regarding the suitability of products for certain types of applications are based on XI BNANG 's knowledge of typical requirements that are often placed on XI BNANG products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer 's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters , including typical parameters , must be validated for each customer application by the customer 's technical experts. Product specifications do not expand or otherwise modify XI BNANG 's terms and conditions of purchase, including but not limited to the warranty expressed therein.